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Vanadium pentoxide interfacial layer enables high-performance all-solid-state thin film batteries

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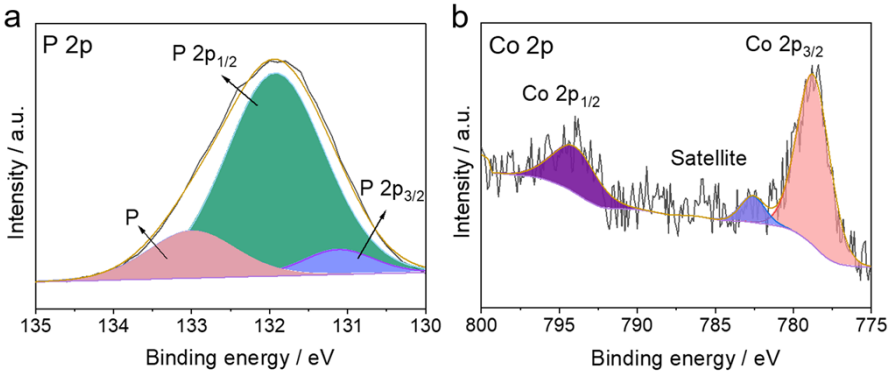

Figure S1. High-resolution XPS spectra for elemental (a) P 2p and (b) Co 2p.

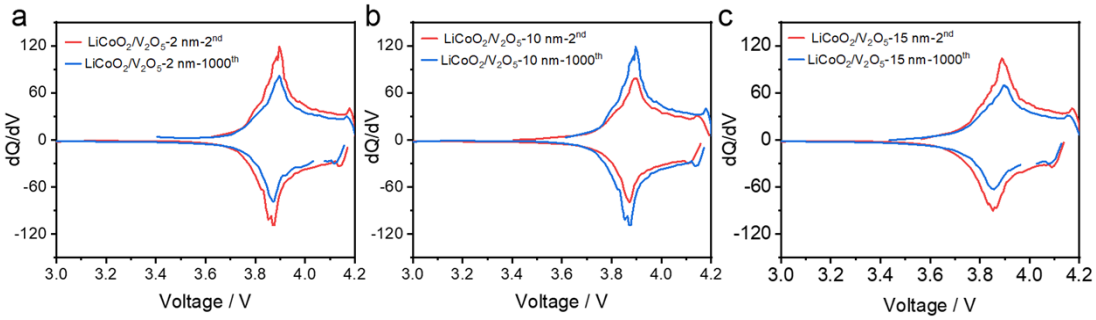

Figure S2. The differential capacity (dQ/dV) versus voltage derived from the 2nd and 1000th charge-discharge curves of TFBs based on (a) $LiCoO_2/V_2O_5$-2 nm/LiPON/Li, (b) $LiCoO_2/V_2O_5$-10 nm/LiPON/Li and (c) $LiCoO_2/V_2O_5$-15 nm/LiPON/Li structures.